









 	<h2 style="color: red;">FQB34P10TM</h2> <p>Hersteller-Teilenummer: FQB34P10TM</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 100V 33.5A D2PAK</p> <p>Datenblätter:  FQB34P10TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 25948 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB34P10TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 100V 33.5A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	25948 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 155W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	33.5A (Tc)
Rds On (Max) @ Id, Vgs	60 mOhm @ 16.75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	110nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2910pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)



















































FQB34P10TM ist neu im Original, Suche FQB34P10TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB34P10TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB34P10TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB34N20TM_AM002 Fairchild/ON Semiconductor FQB34N20TM_AM002 Fairchild/ON Semiconductor</p>	 <p>FQB34P10TM_F085 Fairchild/ON Semiconductor FQB34P10TM_F085 Fairchild/ON Semiconductor</p>	 <p>FQB34N20LTM Fairchild/ON Semiconductor MOSFET N-CH 200V 31A D2PAK</p>	 <p>FQB3N25 VB FQB3N25 VB</p>
 <p>FQB34P10TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 33.5A D2PAK</p>	 <p>FQB34P10 FAIRCHI FQB34P10 FAIRCHI</p>	 <p>FQB34P10TM-F085P AMI Semiconductor / ON Semiconductor PMOS D2PAK 100V 60 MOHM</p>	 <p>FQB34P10TM-F085 AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 33.5A D2PAK</p>

heiße Teile

Mehr

 FQB30N06LTM	 FQB30N06TM	 FQB30N06TM	 FQB32N12V2	 FQB32N12V2TM
 FQB32N12V2TM	 FQB32N20	 FQB32N20C	 FQB32N20CTM	 FQB32N20CTM
 FQB32N30	 FQB33N10	 FQB33N10L	 FQB33N10LTM	 FQB33N10LTM
 FQB33N10TM	 FQB33N10TM	 FQB34N20	 FQB34N20L	 FQB34N20LTM
 FQB34N20LTM	 FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10	 FQB34P10TM
 FQB34P10TM_F085	 FQB3N25TM	 FQB3N25TM	 FQB3N30TM	 FQB3N30TM
 FQB3N40TM	 FQB3N40TM	 FQB3N60C	 FQB3N80TM	 FQB3N80TM
 FQB3N90TM	 FQB3N90TM	 FQB3P20TM	 FQB3P20TM	 FQB3P50TM
 FQB3P50TM	 FQB44N10	 FQB44N10TM	 FQB44N10TM	 FQB46N15
 FQB46N15TM	 FQB47P06	 FQB47P06TM	 FQB4N20L	 FQB4N20LTM

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